



DMTH8012LK3Q

## Product Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
00)/	16mΩ @ V <sub>GS</sub> = 10V	50A
80V	21mΩ @ V <sub>GS</sub> = 4.5V	43A

#### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AECQ101, supported by a PPAP and is ideal for use in:

- Engine Management Units
- Motor Control
- DC-DC Converters

#### Features

 Rated to +175°C – Ideal for High Ambient Temperature Environments

80V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

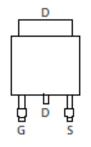
- Low R<sub>DS(ON)</sub> Ensures On-State Losses are Minimized
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)

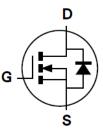


Top View



TO252 (DPAK)

Pin Out Top View



Equivalent Circuit

#### Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH8012LK3Q-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

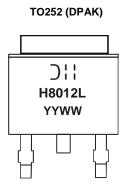
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

 <sup>&</sup>lt;1000ppm antimony compounds.</li>
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are and thermally the same, except



#### **Marking Information**



Dili =Manufacturer's MarkingH8012L = Product Type Marking CodeYYWW = Date Code MarkingYY = Last Two Digits of Year (ex: 14 = 2014)WW = Week Code (01 to 53)

## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V <sub>DSS</sub>	80	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 7) $V_{GS} = 10V$	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	50 35	А
Maximum Continuous Body Diode Forward Current (Note 7)		Is	80	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	80	А
Avalanche Energy, L = 60mH		E <sub>AS</sub>	147	mJ

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	47	°C/W
Total Power Dissipation (Note 7)	PD	60	W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θJC</sub>	2.5	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

7. Device mounted on infinite heat sink and measured by thermal couple attached on bottom heat sink of package.



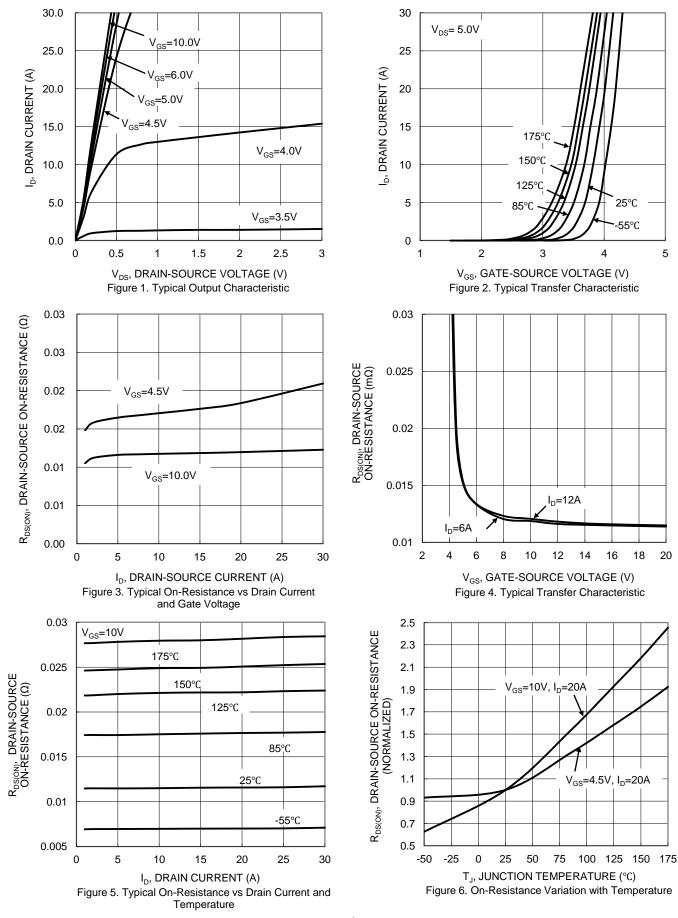
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

<b>••</b> •••			_				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	80	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS} = 64V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)						_	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Braves	_	12.1	16	mΩ	$V_{GS} = 10V, I_D = 12A$	
	R <sub>DS(ON)</sub>	_	14.8	21	11122	$V_{GS} = 4.5V, I_D = 6A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 25A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	_	2051	—			
Output Capacitance	Coss	_	189.9	—	pF	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V, f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	24.6	—			
Gate Resistance	Rg	_	0.44	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	24.1	—			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	46.8	—	nC	101/1 101	
Gate-Source Charge	Q <sub>gs</sub>	_	6.9	—	nc	$V_{DS} = 40V, I_D = 12A$	
Gate-Drain Charge	Q <sub>gd</sub>	_	12.2	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.8	_			
Turn-On Rise Time	t <sub>R</sub>	_	6.5	_	nS	$\label{eq:VDD} \begin{split} V_{DD} &= 40 V, \ V_{GS} = 10 V, \\ I_D &= 12 A, \ R_G = 1.6 \Omega \end{split}$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	17.3	_	15		
Turn-Off Fall Time	tF		4.7	—			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	33.5	_	nS		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	38.9	_	nC	I <sub>F</sub> = 12A, di/dt = 100A/μs	

8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing. Notes:

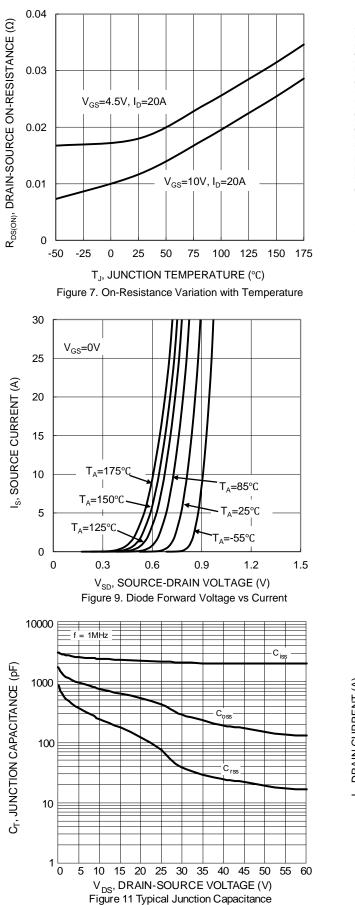


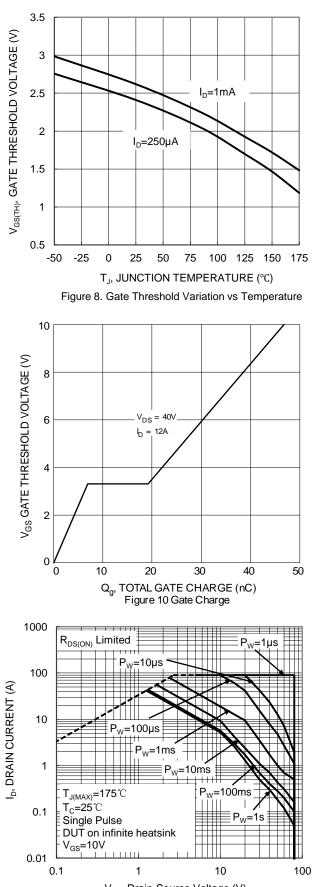
### DMTH8012LK3Q



DMTH8012LK3Q Document number: DS38062 Rev. 1 - 2







 $V_{\text{DS}},$  Drain-Source Voltage (V) Figure 12. SOA, Safe Operation Area



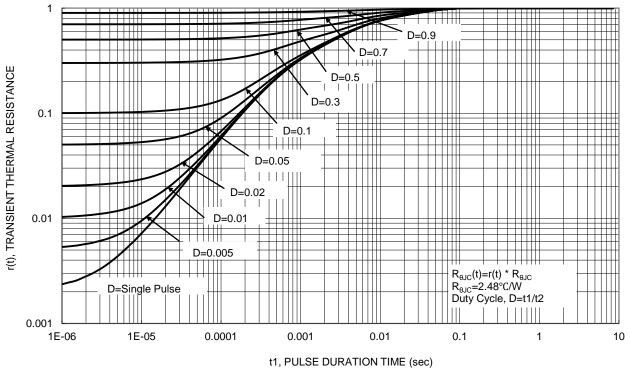
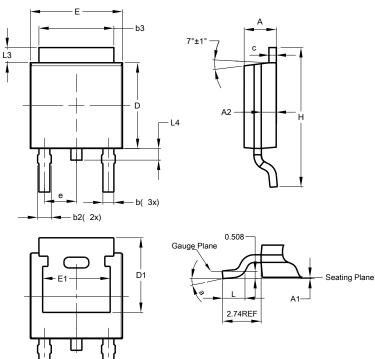


Figure 13. Transient Thermal Resistance



#### **Package Outline Dimensions**

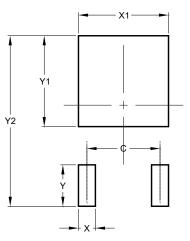
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)				
Dim	Min	Max	Тур	
Α	2.19	2.39	2.29	
A1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
С	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21		_	
е	_	—	2.286	
Е	6.45	6.70	6.58	
E1	4.32	_	_	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	_	
All	All Dimensions in mm			

#### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



TO252 (	DPAK)

Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
Y2	10.700		

TO252 (DPAK)



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